

# Development of Neganov-Luke light detectors for a rare event experiment

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Low Temperature Detector  
Development and Physics

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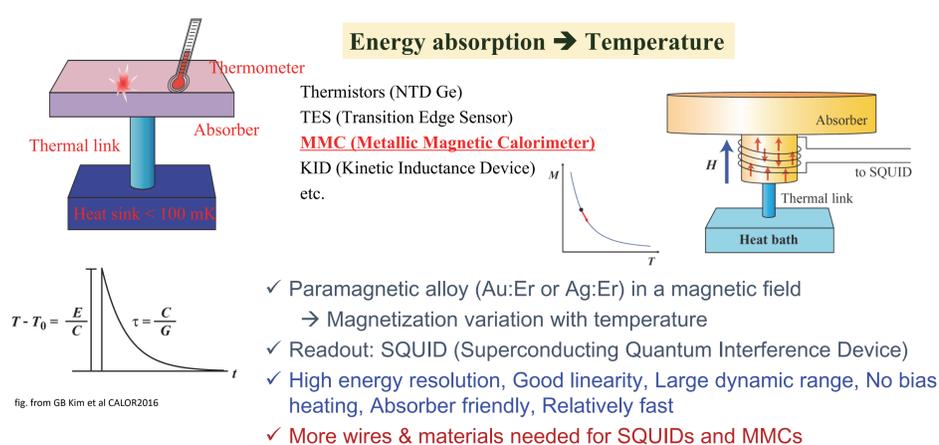
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## Abstract

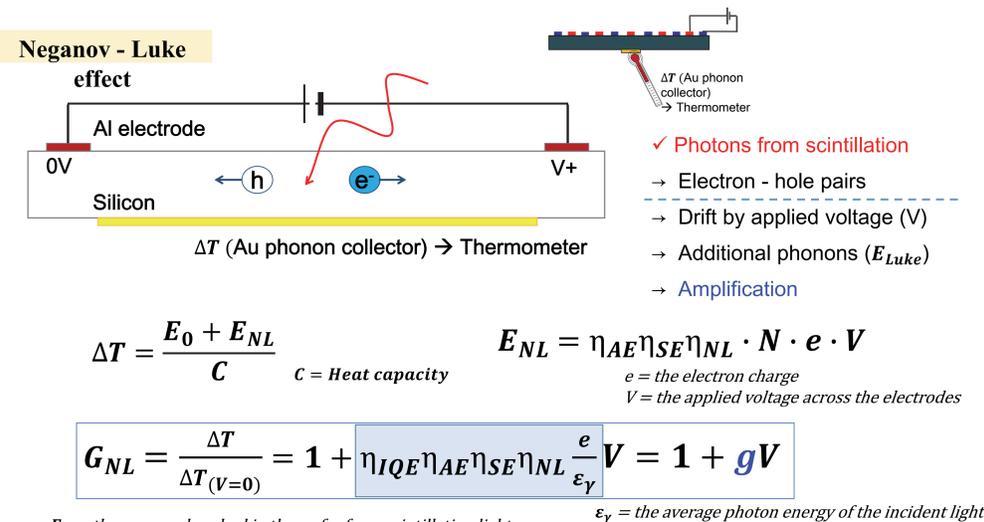
We report a progress of a light detector development with Neganov-Luke (NL) phonon amplification. Double comb-like electrodes were fabricated on an intrinsic Si wafer to apply an electric field. A metallic magnetic calorimeter was used for a sensitive measurement of the temperature increase originating from light absorption in the wafer and NL phonon amplification. The NL light detector was applied to a simultaneous detection of heat and light signals from a ZnWO<sub>4</sub> scintillating crystal. Clear amplification in light signals was obtained in various voltages applied to the electrodes while no change on the heat signals was found. The voltage dependence of the measured gain was investigated with a few efficiency parameters such as a saturation voltage to suppress recombination of electron-hole pairs and a heat generation efficiency of the NL effect.

## Low temperature detectors

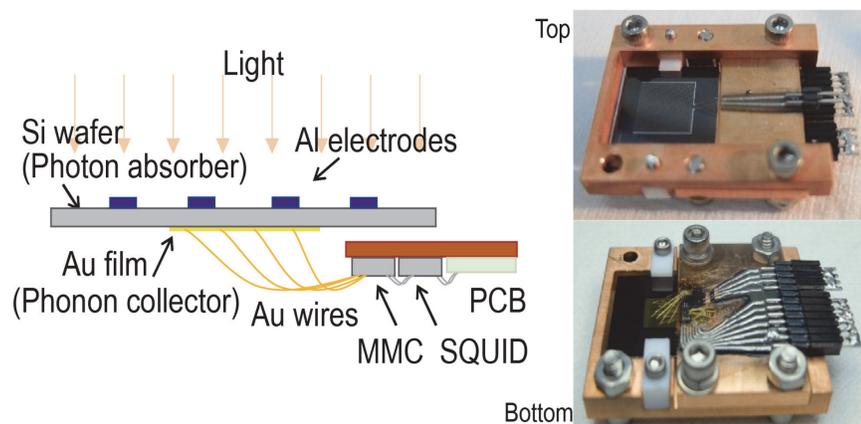
“Calorimetric measurement of heat signals at mK temperatures”



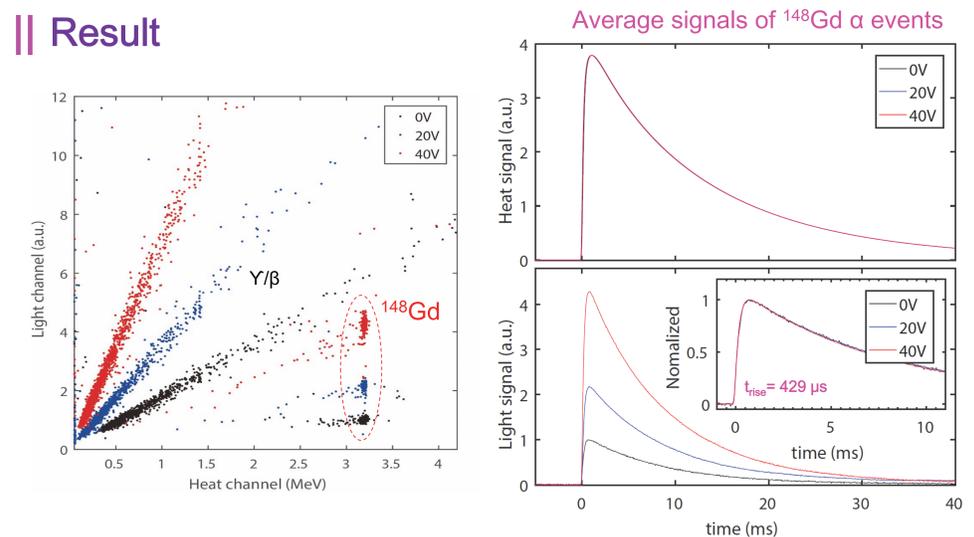
## Phonon amplification in scintillation detection



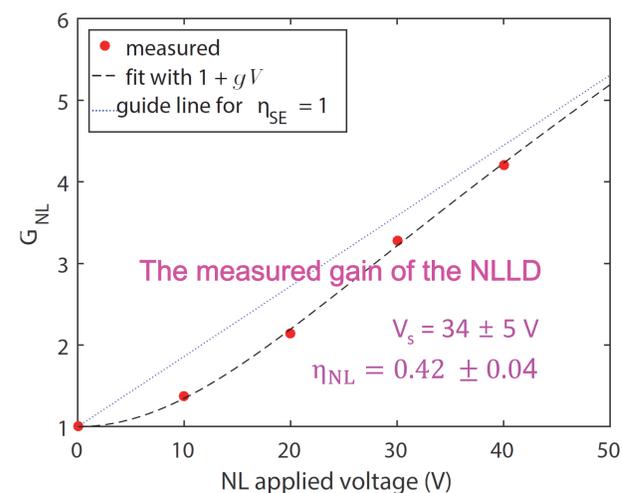
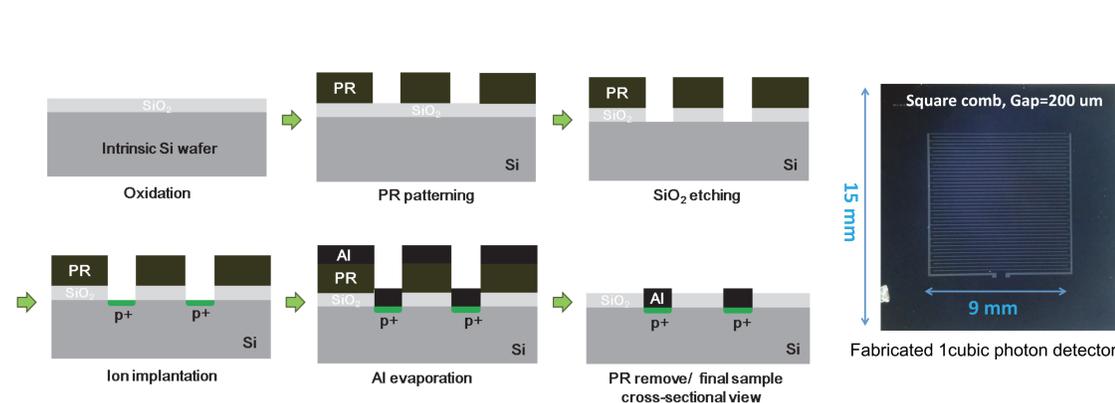
## Simultaneous phonon-scintillation detection



## Result



## Phonon amplified light detector design and fabrication



## Discussion

The evident phonon amplification in the light detector makes it possible to introduce distinctive efficiency parameters of the NL gain. The double comb-like electrodes with 200 μm gap characterizes a saturation voltage of 44 V for 90% efficiency of recombination suppression.

Moreover, an average of about 45% heat generation is yielded for an unrecombined pair of electron and hole from the full amplification of the NL effect. These parameters indicate that an NLLD prepared in the present method is expected to measure a 40-eV equivalent signal from a single photon absorption in the substrate with an NL voltage of 100 V.

Combined with a sensitive calorimetric sensor, it is possible to compose a detector with a single photon sensitivity. Moreover, this kind low-threshold can be applied to probe nuclear recoils in the target such as low-mass DM detection or neutrino coherent scatterings.